

GaAs MMIC SPDT NON-REFLECTIVE SWITCH, DC - 28.0 GHz

Typical Applications

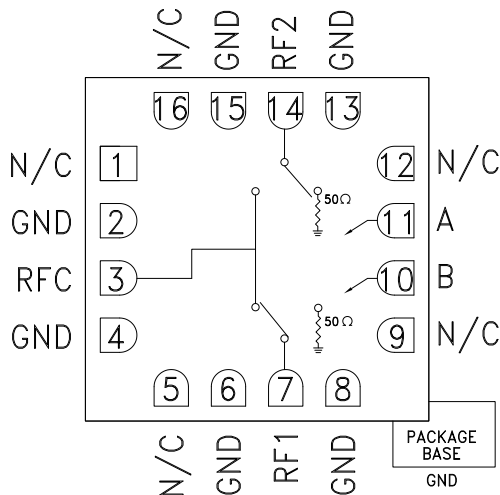
The HMC547ALC3 is ideal for:

- Fiber Optics & Broadband Telecom
- Microwave Radio & VSAT
- Military Radios, Radar, & ECM
- Test Instrumentation

Features

- High Isolation: 45 dB @ 10 GHz
39 dB @ 20 GHz
- Low Insertion Loss: 1.9 dB @ 10 GHz
2.2 dB @ 20 GHz
- Fast Switching: 6 ns
- Non-Reflective Design
- 16 Lead Ceramic 3x3 mm SMT Package: 9mm²

Functional Diagram



General Description

The HMC547ALC3 is a general purpose broadband high isolation non-reflective GaAs pHEMT SPDT switch in a ceramic 3x3 mm leadless surface mount package. Covering DC to 28.0 GHz, the switch offers over 40 dB isolation and less than 2 dB insertion loss at midband. The wide bandwidth, fast switching, and compact size make this absorptive SPDT ideal for military EW/ECM and test equipment applications. The switch operates using complementary negative control voltage logic lines of -5/0V and requires no bias supply.

Electrical Specifications, $T_A = +25^\circ\text{C}$, With 0/-5V Control, 50 Ohm System

Parameter	Frequency	Min.	Typ.	Max.	Units
Insertion Loss	DC - 10.0 GHz		1.9	2.4	dB
	10.0 - 20.0 GHz		2.2	2.8	dB
	20.0 - 26.0 GHz		2.8	3.4	dB
	26.0 - 28.0 GHz		3.1	3.7	dB
Isolation	DC - 10.0 GHz	40	45		dB
	10.0 - 20.0 GHz	34	40		dB
	20.0 - 28.0 GHz	30	34		dB
Return Loss	"On State"				
	DC - 28.0 GHz		17		dB
Return Loss RF1, RF2	"Off State"				
	DC - 10.0 GHz		25		dB
	10.0 - 20.0 GHz		15		dB
Input Power for 1 dB Compression	20.0 - 28.0 GHz		8		dB
	DC - 0.5 GHz		16		dBm
Input Third Order Intercept (Two-Tone Input Power= +7 dBm Each Tone)	0.5 - 28.0 GHz	20	26		dBm
	DC - 0.5 GHz		35		dBm
Switching Characteristics	0.5 - 28.0 GHz		46		dBm
	DC - 28.0 GHz		3		ns
tRISE, tFALL (10/90% RF)			6		ns
tON, tOFF (50% CTL to 10/90% RF)					ns

HMC547ALC3* PRODUCT PAGE QUICK LINKS

Last Content Update: 12/18/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- HMC547ALC3 Evaluation Board

DOCUMENTATION

Data Sheet

- HMC547ALC3: GaAs MMIC SPDT Non-Reflective Switch, DC - 28.0 GHz Data Sheet

TOOLS AND SIMULATIONS

- HMC547ALC3 S-Parameters

REFERENCE MATERIALS

Quality Documentation

- Semiconductor Qualification Test Report: PHEMT-J (QTR: 2013-00285)

Technical Articles

- Calibration-Free Return Loss Measurement

DESIGN RESOURCES

- HMC547ALC3 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC547ALC3 EngineerZone Discussions.

SAMPLE AND BUY

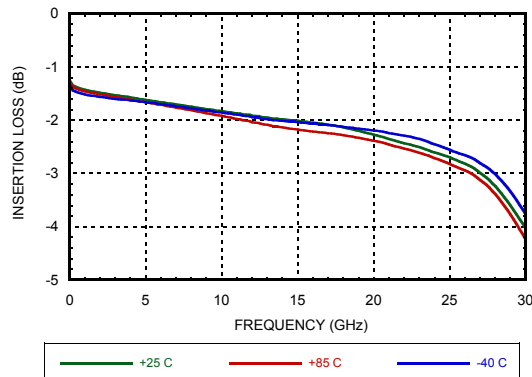
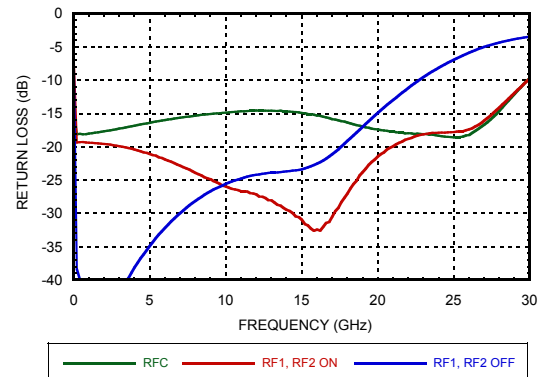
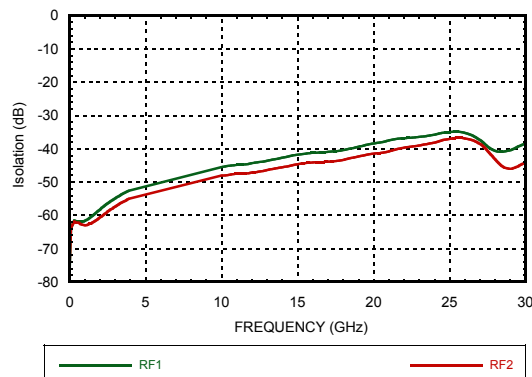
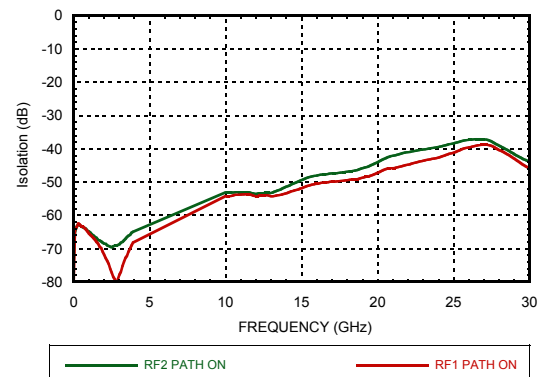
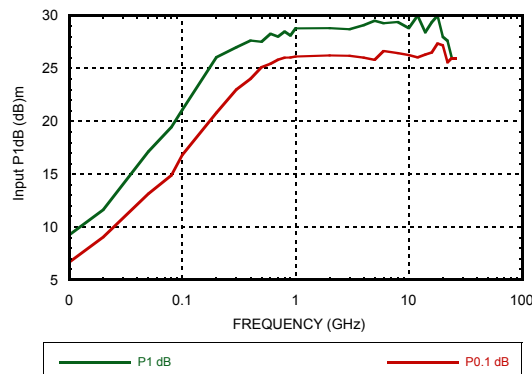
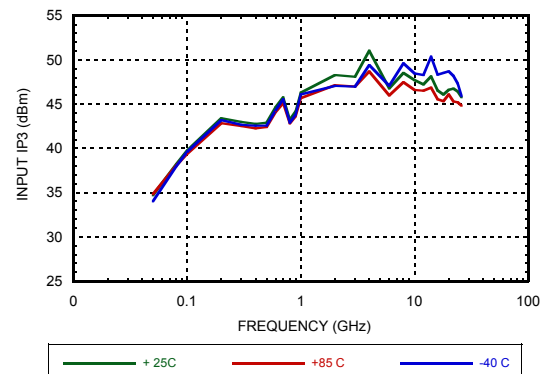
Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK

Submit feedback for this data sheet.

**GaAs MMIC SPDT NON-REFLECTIVE
SWITCH, DC - 28.0 GHz**
Insertion Loss

Return Loss

Isolation Between Ports RFC and RF1/RF2

Isolation Between Ports RF1 and RF2

**Input P1dB and P0.1dB
Compression Point**

Input Third Order Intercept Point


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Absolute Maximum Ratings

RF Input Power (Vctl = -5V)	+29 dBm
Control Voltage Range (A & B)	+0.5V to -7.5 V
Hot Switch Power Level (Vctl = -5V)	+23 dBm
Channel Temperature	150 °C
Continuous Pdiss (T=85°C) (derate 8.5 mW/°C above 85°C) (Insertion Loss Path)	0.55W
Thermal Resistance (Insertion Loss Path)	118 °C/W
Terminated Power Level (Vctl = -5V)	+25dBm
Continuous Pdiss (T=85°C) (derate 5.0 mW/°C above 85°C) (Terminated Path)	0.32W
Thermal Resistance (Terminated Path)	200 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 0; Passed 150V

Control Voltages

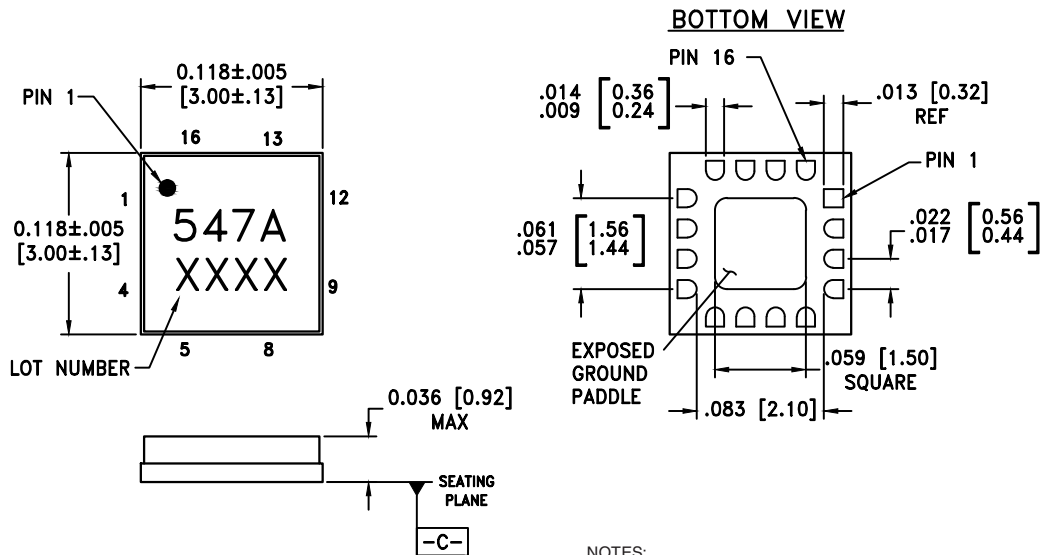
State	Bias Condition
Low	0 to -0.2V @ 10 uA Max.
High	-5V @ 10 uA Typ. to -7V @ 40 uA Typ. (± 0.5V)

Truth Table

Control Input		Signal Path State	
A	B	RFC to RF1	RFC to RF2
High	Low	On	Off
Low	High	Off	On



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

**GaAs MMIC SPDT NON-REFLECTIVE
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Outline Drawing

NOTES:

1. PACKAGE BODY MATERIAL: ALUMINA.
2. LEAD AND GROUND PADDLE PLATING: GOLD FLASH OVER NICKEL.
3. DIMENSIONS ARE IN INCHES (MILLIMETERS).
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
5. PACKAGE WARP SHALL NOT EXCEED 0.05MM DATUM .
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

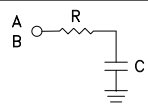
Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]
HMC547ALC3	Alumina, White	Gold over Nickel	MSL3 ^[1]	547A XXXX

[1] Max peak reflow temperature of 260 °C

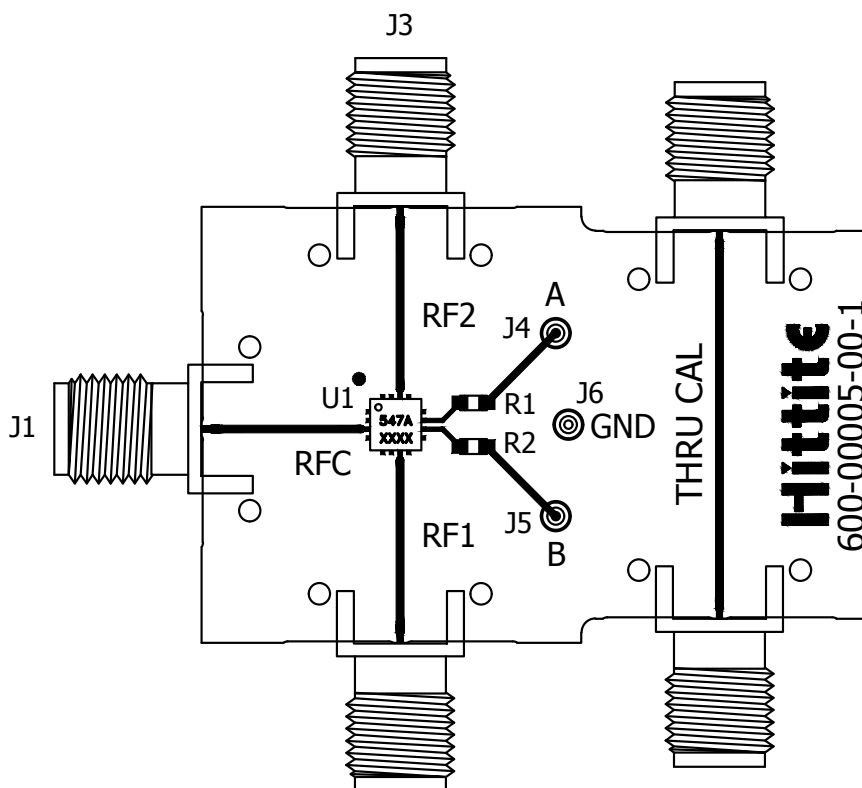
[2] 4-Digit lot number XXXX

**GaAs MMIC SPDT NON-REFLECTIVE
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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 5, 9, 12, 16	N/C	This pin should be connected to PCB RF ground to maximize isolation	
2, 4, 6, 8, 13, 15	GND	Package bottom has exposed metal paddle that must also be connected to PCB RF ground.	
3, 7, 14	RFC, RF1, RF2	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required if RF line potential is not equal to 0V.	
10	B	See truth table and control voltage table.	
11	A	See truth table and control voltage table.	

**GaAs MMIC SPDT NON-REFLECTIVE
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Evaluation PCB



List of Materials for Evaluation PCB EV1HMC547ALC3 ^[1]

Item	Description
J1 - J3	PCB Mount SRI SMA Connector
J4 - J6	DC Pin
R1 - R2	100 Ohm Resistor, 0603 Pkg.
U1	HMC547ALC3 SPDT Switch
PCB ^[2]	600-00005-00-1 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 Ohm impedance and the package ground leads and package bottom should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Analog Devices upon request.